JAN 1 2 2007

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

n re the Application of:)	Group Art Unit: 2812
Kurita, et al.)	
Serial No. 09/464,362)	Examiner: Simkovic, V

Filed: December 15, 1999)
For: SPUTTERED TUNGSTEN SILICON)

NITRIDE DIFFUSION BARRIER FOR)
POLYMETAL GATE STRUCTURES)

V. TECHNOLOGY CENTER?

RESPONSE TO ELECTION/RESTRICTION REQUIREMENT

Assistant Commissioner for Patents Washington, DC 20231

Dear Sirs:

This is in response to an Office Action dated December 11, 2000, for which a response is due by Jan. 11, 2001. Please enter and consider the following.

In response to the Examiner's election/restriction requirement, the applicants hereby elect Group I, claims 1-32, 33-44, 50-55.

Applicants note that pending claims 45-49 were not included in either group. Therefore, applicants traverse the election/restriction requirement to the extent that claims 45-49 should be included in Group I. Dependent claims 45, 46 and 48 all depend directly from claims in Group I, claim 47 depends from claim 46, and claim 49 depends from claim 48.

In view of the above, examination on the merits is respectfully requested. If necessary, please charge any deficiency in fees relating to this paper to deposit account no. 50-0585. A duplicate copy of this paper is enclosed.

Respectfully submitted,

Dated: January 11, 2001

Alan S. Raynes / Reg. No. 39,809

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I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Assistant Commissioner of Patents, Washington, D.C. 20231 on <u>Jan. 11, 2001</u>.

Alan S. Raynes, Reg. No. 39,809

Name of Applicant, assignee, or Registered Rep.

Alan S. Raynes

Jan. 11, 201